



1A, 100-200V Ultrafast Surface Mount Rectifier

FEATURES

- AEC-Q101 qualified
- Planar technology
- Ideal for automated placement
- Low reverse leakage
- Moisture sensitivity level: level 1, per J-STD-020
- RoHS Compliant
- Halogen-free according to IEC 61249-2-21

ΔΙ	DD	 CI	T	n	NS
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- High frequency switching
- DC/DC converter
- Snubber

MECHANICAL DATA

- Case: Micro SMA
- Molding compound meets UL 94V-0 flammability rating
- Terminal: Matte tin plated leads, solderable per J-STD-002
- Meet JESD 201 class 2 whisker test
- Polarity: Indicated by cathode band
- Weight: 0.006g (approximately)

KEY PARAMETERS				
PARAMETER	VALUE	UNIT		
I _F	1	Α		
V_{RRM}	100-200	V		
I _{FSM}	28	Α		
T _{J MAX}	175	°C		
Package	Micro SMA			











PARAMETER	SYMBOL	PU1BMH	PU1DMH	UNIT	
Marking code on the device			P1	P2	
Repetitive peak reverse voltage	V_{RRM}	100	200	V	
Reverse voltage, total rms value	$V_{R(RMS)}$	70	140	V	
DC blocking voltage	V _{DC}	100	200	V	
Forward current	I _F	1		Α	
Surge peak forward current single 8.3ms at T _A = 25°0			28		Α
half sine-wave superimposed on rated load per diode	1.0ms at T _A = 25°C	IFSM	52		Α
Junction temperature	TJ	-55 to +175		°C	
Storage temperature	T _{STG}	-55 to +175		°C	



THERMAL PERFORMANCE					
PARAMETER	SYMBOL	TYP	UNIT		
Junction-to-lead thermal resistance	$R_{\Theta JL}$	28	°C/W		
Junction-to-ambient thermal resistance	$R_{\Theta JA}$	60	°C/W		
Junction-to-case thermal resistance	R _{eJC}	34	°C/W		

Thermal Performance Note: Units mounted on PCB (5mm x 5mm Cu pad test board)

ELECTRICAL SPECIFICATIONS (T _A = 25°C unless otherwise noted)					
PARAMETER	CONDITIONS	SYMBOL	TYP	MAX	UNIT
	$I_F = 0.5A, T_J = 25^{\circ}C$		0.84	-	V
Forward voltage ⁽¹⁾	$I_F = 1.0A, T_J = 25^{\circ}C$	V	0.90	1.05	V
Forward voltage	I _F = 0.5A, T _J = 125°C	V _F	0.70	-	V
	I _F = 1.0A, T _J = 125°C		0.76	0.90	V
Reverse current @ rated V _R ⁽²⁾	T _J = 25°C		-	1	μA
Reverse current & rated v _R	T _J = 125°C	- I _R	-	15	μA
Payaraa raaayary tima	$I_F = 0.5A$, $I_R = 1.0A$, $I_{rr} = 0.25A$		-	25	ns
Reverse recovery time	$I_F = 1.0A$, di/dt = 50A/ μ s, $V_R = 30V$	t _{rr}	36	-	
Reverse recovery current		I _{RM}	3.4	-	Α
Reverse recovery charge	$I_F = 1.0A$, di/dt = 200A/ μ s, $V_R = 100V$	Q _{rr}	40	-	nC
Reverse recovery time		t _{rr}	24	-	ns
Junction capacitance	1MHz, V _R = 4.0V	CJ	18	-	pF

Notes:

- (1) Pulse test with PW = 0.3ms
- (2) Pulse test with PW = 30ms

ORDERING INFORMATION					
ORDERING CODE ⁽¹⁾	PACKAGE	PACKING			
PU1xMH M3G	Micro SMA	3000 / 7" reel			

Notes:

(1) "x" defines voltage from 100V(PU1BMH) to 200V(PU1DMH)



CHARACTERISTICS CURVES

 $(T_A = 25^{\circ}C \text{ unless otherwise noted})$

Fig.1 Forward Current Derating Curve

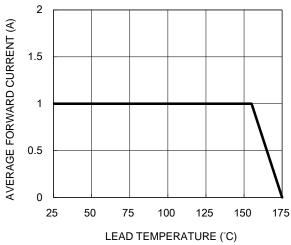


Fig.3 Typical Reverse Characteristics



Fig.2 Typical Junction Capacitance

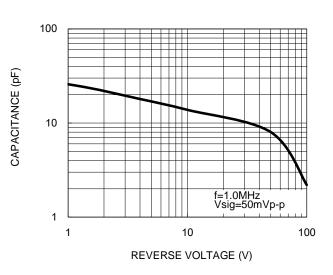
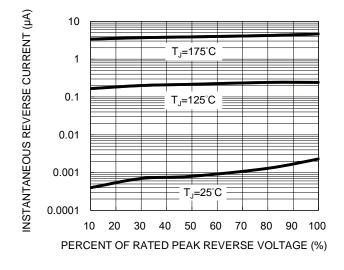


Fig.4 Typical Forward Characteristics



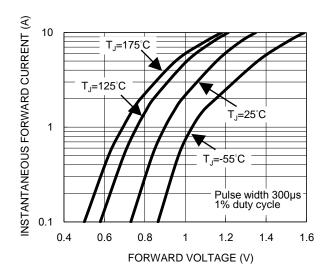
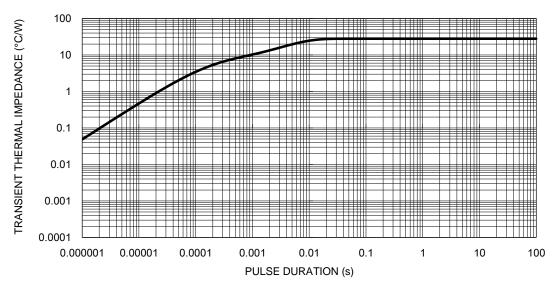


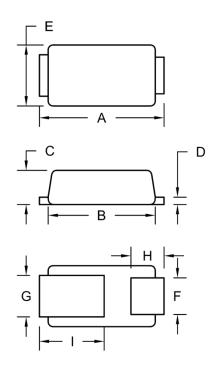
Fig.5 Typical Transient Thermal Impedance





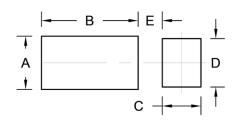
PACKAGE OUTLINE DIMENSIONS (Unit: Millimeters)

Micro SMA



DIM.	Unit (mm)		Unit (inch)	
Dilvi.	Min.	Max.	Min.	Max.
Α	2.30	2.70	0.091	0.106
В	2.10	2.30	0.083	0.091
С	0.63	0.73	0.025	0.029
D	0.10	0.20	0.004	0.008
E	1.15	1.35	0.045	0.053
F	0.65	0.85	0.026	0.034
G	0.75	0.95	0.030	0.037
Н	0.55	0.75	0.022	0.030
I	1.10	1.50	0.043	0.059

SUGGESTED PAD LAYOUT



Symbol	Unit (mm)	Unit (inch)
Α	1.10	0.043
В	2.00	0.079
С	0.80	0.031
D	1.00	0.039
E	0.50	0.020

MARKING DIAGRAM



P/N = Marking Code YW = Date Code



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